

65,536-WORD BY 16-BIT CMOS STATIC RAM

DESCRIPTION

The TC55V1664BJ/BFT is a 1,048,576 bits high speed static random access memory organized as 65,536 words by 16 bits using CMOS technology, and operated from a single 3.3V supply. Toshiba's CMOS technology and advanced circuit form provide high speed feature.

The TC55V1664BJ/BFT has low power feature with device control using chip enable ($\overline{\text{CE}}$), and has output enable ($\overline{\text{OE}}$) for fast memory access. Also it allows lower and upper byte access by data byte control ($\overline{\text{LB}}$, $\overline{\text{UB}}$). The TC55V1664BJ/BFT is suitable for use in cache memory where high speed is required, and high speed storage. All inputs and outputs are directly LVTTL compatible.

The TC55V1664BJ/BFT is packaged in 44-pin plastic SOJ and TSOP with 400 mil width for high density surface assembly.

FEATURES

- Fast access time :

TC55V1664BJ/BFT-10	10ns (MAX)
TC55V1664BJ/BFT-12	12ns (MAX)

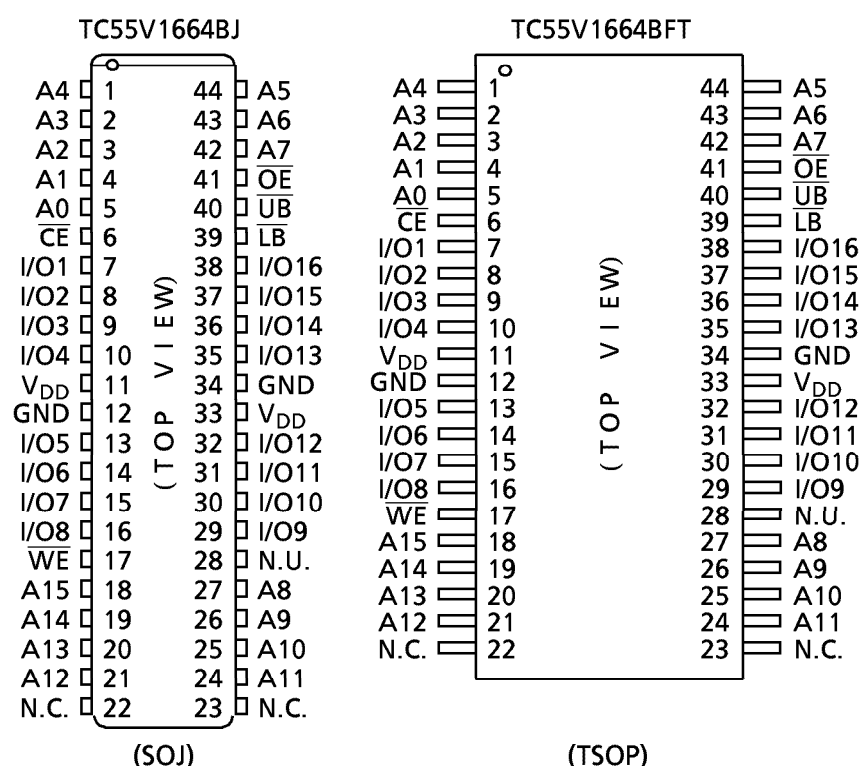
- Low power dissipation

Cycle Time	10	12	15	20	ns
Operation (MAX)	230	190	170	150	mA

Standby : 2mA (MAX)

- 3.3V single power supply : $3.3V \pm 0.3V$
- Fully static operation
- All Inputs and Outputs : LVTTTL compatible
- Output buffer control : $\overline{OE}$
- Data byte control
 $\overline{LB}$ (I/O1 to I/O8), $\overline{UB}$ (I/O9 to I/O16)
- Package:
SOJ44-P-400-1.27 (BJ) (Weight : 1.64gm Typ)
TSOP II 44-P-400-0.80 (BFT) (Weight : 0.45gm Typ)

PIN CONNECTION



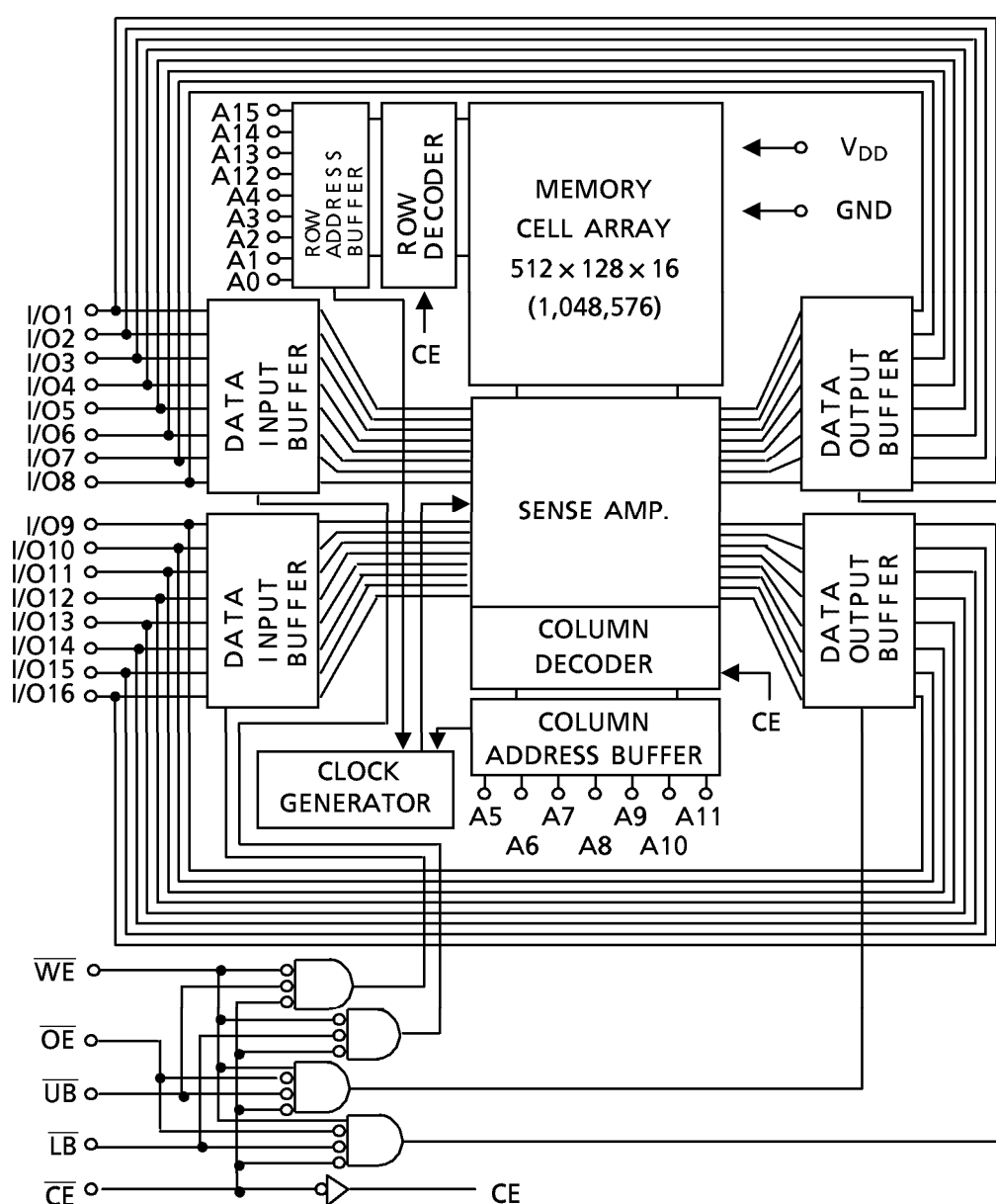
PIN NAMES

A0 to A15	Address Inputs
I/O1 to I/O16	Data Inputs / Outputs
$\overline{CE}$	Chip Enable Input
$\overline{WE}$	Write Enable Input
$\overline{OE}$	Output Enable Input
$\overline{LB}, \overline{UB}$	Data Byte Control Inputs
V_{DD}	Power (+ 3.3V)
GND	Ground
N.C.	No Connection
N.U.	Not Usable (Input)

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BLOCK DIAGRAM



MAXIMUM RATINGS

SYMBOL	RATING	VALUE	UNIT
V _{DD}	Power Supply Voltage	– 0.5 to 4.6	V
V _{IN}	Input Terminal Voltage	– 0.5 * to 4.6	V
V _{I/O}	Input / Output Terminal Voltage	– 0.5 * to V _{DD} + 0.5**	V
P _D	Power Dissipation	0.95	W
T _{solder}	Soldering Temperature (10s)	260	°C
T _{strg}	Storage Temperature	– 65 to 150	°C
T _{opr}	Operating Temperature	– 10 to 85	°C

* : -1.5V with a pulse width of 20% · t_{RC} min (4ns max)
 ** : V_{DD}+1.5V with a pulse width of 20% · t_{RC} min (4ns max)

DC RECOMMENDED OPERATING CONDITIONS ($T_a = 0^\circ$ to 70°C)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNIT
V_{DD}	Power Supply Voltage	3.0	3.3	3.6	V
V_{IH}	Input High Voltage	2.0	–	$V_{DD} + 0.3^{**}$	V
V_{IL}	Input Low Voltage	-0.3^*	–	0.8	V

* : -1.0V with a pulse width of $20\% \cdot t_{RC}$ min (4ns max)** : $V_{DD} + 1.0\text{V}$ with a pulse width of $20\% \cdot t_{RC}$ min (4ns max)DC and OPERATING CHARACTERISTICS ($T_a = 0^\circ$ to 70°C , $V_{DD} = 3.3\text{V} \pm 0.3\text{V}$)

SYMBOL	PARAMETER	TEST CONDITION		MIN	TYP	MAX	UNIT
I _{IL}	Input Leakage Current (Except NU pin)	V _{IN} = 0 to V _{DD}		– 1	–	1	μA
I _{LO}	Output Leakage Current	CE = V _{IH} or WE = V _{IL} or OE = V _{IH} V _{OUT} = 0 to V _{DD}		– 1	–	1	μA
I _{I(NU)}	Input Current (NU pin)	V _{IN} = 0 to 0.8V		– 1	–	20	μA
		V _{IN} = 0 to 0.2V		– 1	–	1	
V _{OH}	Output High Voltage	I _{OH} = – 2mA		2.4	–	–	V
		I _{OH} = – 100μA		V _{DD} – 0.2	–	–	
V _{OL}	Output Low Voltage	I _{OL} = 2mA		–	–	0.4	
		I _{OL} = 100μA		–	–	0.2	
I _{DDO}	Operating Current	CE = V _{IL} , I _{out} = 0mA Other Inputs = V _{IH} / V _{IL}	tcycle = 10ns	–	–	230	mA
			tcycle = 12ns	–	–	190	
			tcycle = 15ns	–	–	170	
			tcycle = 20ns	–	–	150	
I _{DDS1}	Standby Current	CE = V _{IH} , Other Inputs = V _{IH} / V _{IL}		–	–	50	mA
I _{DDS2}		CE = V _{DD} – 0.2V Other Inputs = V _{DD} – 0.2V or 0.2V		–	–	2	

CAPACITANCE ($T_a = 25^\circ\text{C}$, $f = 1.0\text{MHz}$)

SYMBOL	PARAMETER	TEST CONDITION	MAX	UNIT
C_{IN}	Input Capacitance	$V_{IN} = \text{GND}$	6	pF
$C_{I/O}$	Input/Output Capacitance	$V_{I/O} = \text{GND}$	8	pF

NOTE : This parameter is periodically sampled and is not 100% tested.

OPERATING MODE

MODE	$\overline{\text{CE}}$	$\overline{\text{OE}}$	$\overline{\text{WE}}$	$\overline{\text{LB}}$	$\overline{\text{UB}}$	I/O1 to I/O8	I/O9 to I/O16	POWER
Read	L	L	H	L	L	Output	Output	I_{DDO}
				H	L	High Impedance	Output	I_{DDO}
				L	H	Output	High Impedance	I_{DDO}
Write	L	X	L	L	L	Input	Input	I_{DDO}
				H	L	High Impedance	Input	I_{DDO}
				L	H	Input	High Impedance	I_{DDO}
Outputs Disable	L	H	H	X	X	High Impedance	High Impedance	I_{DDO}
	L	X	X	H	H			
Standby	H	X	X	X	X	High Impedance	High Impedance	I_{DDS}

X : H or L

NOTE : N.U. pin must be kept open electrically or pulled down to GND level or less than 0.8V.
Applying a voltage more than 0.8V to N.U. pin is prohibited.

AC CHARACTERISTICS (Ta = 0° to 70°C ⁽¹⁾, VDD = 3.3V ± 0.3V)

READ CYCLE

SYMBOL	PARAMETER	TC55V1664BJ/BFT-10		TC55V1664BJ/BFT-12		UNIT
		MIN	MAX	MIN	MAX	
t _{RC}	Read Cycle Time	10	–	12	–	ns
t _{ACC}	Address Access Time	–	10	–	12	
t _{CO}	$\overline{\text{CE}}$ Access Time	–	10	–	12	
t _{OE}	$\overline{\text{OE}}$ Access Time	–	5	–	6	
t _{BA}	$\overline{\text{UB}}, \overline{\text{LB}}$ Access Time	–	5	–	6	
t _{OH}	Output Data Hold Time from Address Change	3	–	3	–	
t _{COE}	Output Enable Time from $\overline{\text{CE}}$	3	–	3	–	
t _{OEE}	Output Enable Time from $\overline{\text{OE}}$	1	–	1	–	
t _{BE}	Output Enable Time from $\overline{\text{UB}}, \overline{\text{LB}}$	1	–	1	–	
t _{COD}	Output Disable Time from $\overline{\text{CE}}$	–	6	–	7	
t _{ODO}	Output Disable Time from $\overline{\text{OE}}$	–	6	–	7	
t _{BD}	Output Disable Time from $\overline{\text{UB}}, \overline{\text{LB}}$	–	6	–	7	

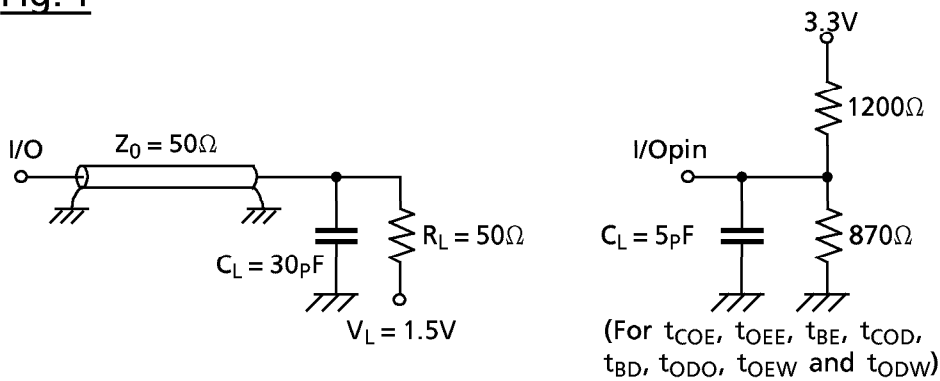
WRITE CYCLE

SYMBOL	PARAMETER	TC55V1664BJ/BFT-10		TC55V1664BJ/BFT-12		UNIT
		MIN	MAX	MIN	MAX	
t _{WC}	Write Cycle Time	10	–	12	–	ns
t _{WP}	Write Pulse Width	7	–	8	–	
t _{CW}	Chip Enable to End of Write	8	–	8	–	
t _{BW}	$\overline{\text{UB}}, \overline{\text{LB}}$ Enable to End of Write	8	–	8	–	
t _{AW}	Address Valid to End of Write	8	–	8	–	
t _{AS}	Address Set Up Time	0	–	0	–	
t _{WR}	Write Recovery Time	0	–	0	–	
t _{DS}	Data Set Up Time	6	–	7	–	
t _{DH}	Data Hold Time	0	–	0	–	
t _{OE_W}	Output Enable Time from $\overline{\text{WE}}$	1	–	1	–	
t _{OD_W}	Output Disable Time from $\overline{\text{WE}}$	–	6	–	7	

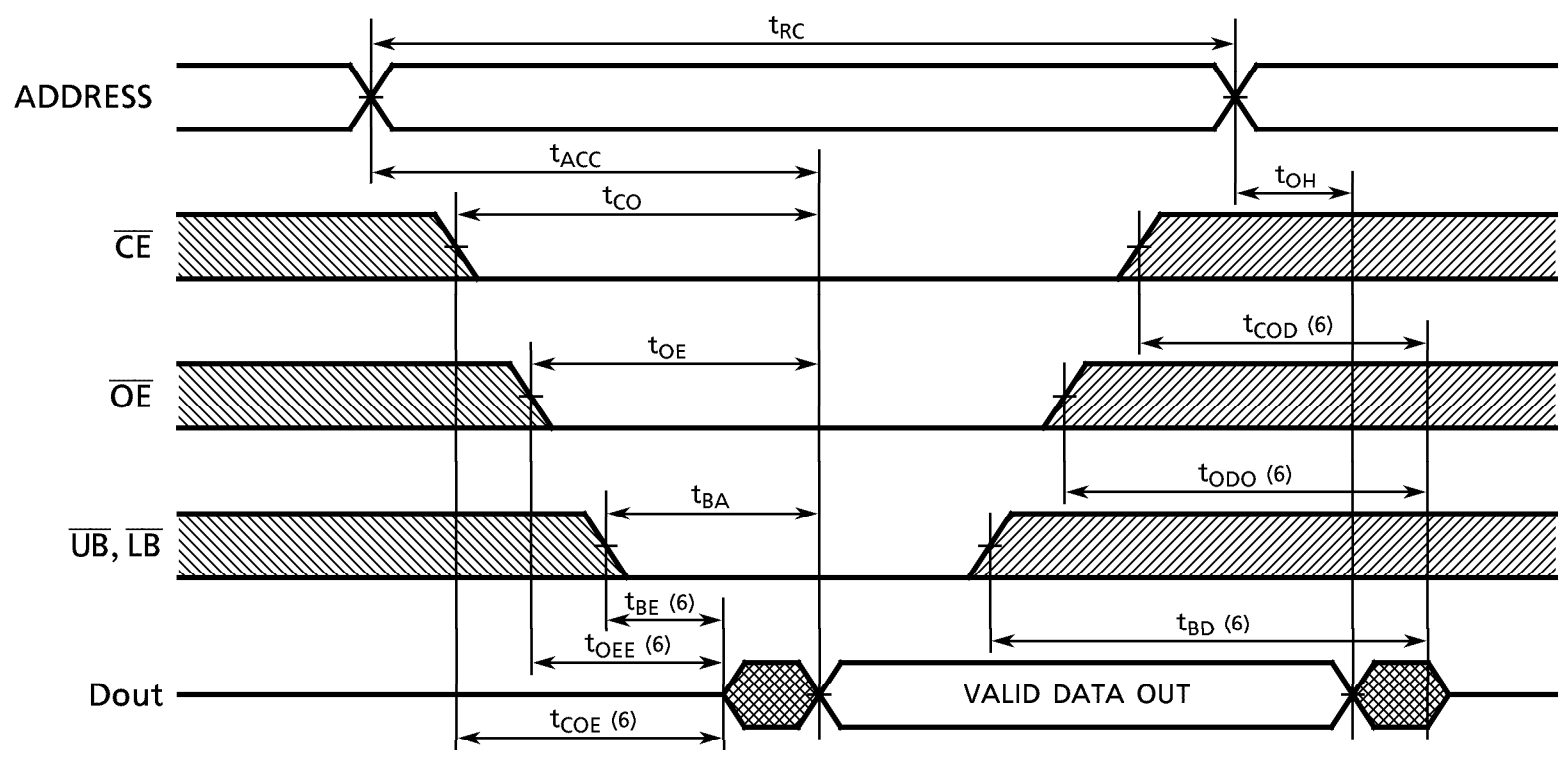
AC TEST CONDITIONS

Input Pulse Level	3.0V/0.0V
Input Pulse Rise and Fall Time	2ns
Input Timing Measurement Reference Level	1.5V
Output Timing Measurement Reference Level	1.5V
Output Load	Fig. 1

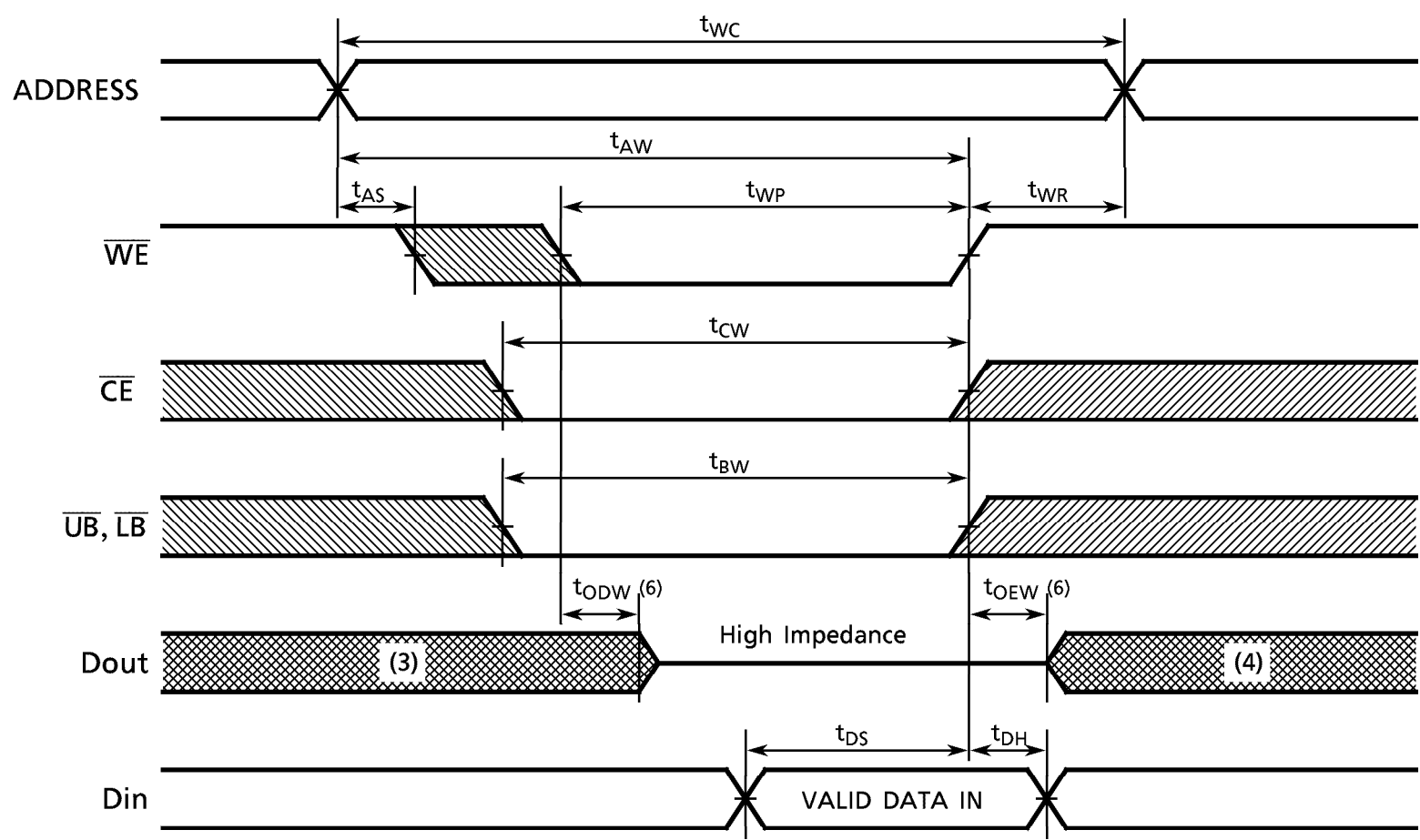
Fig. 1



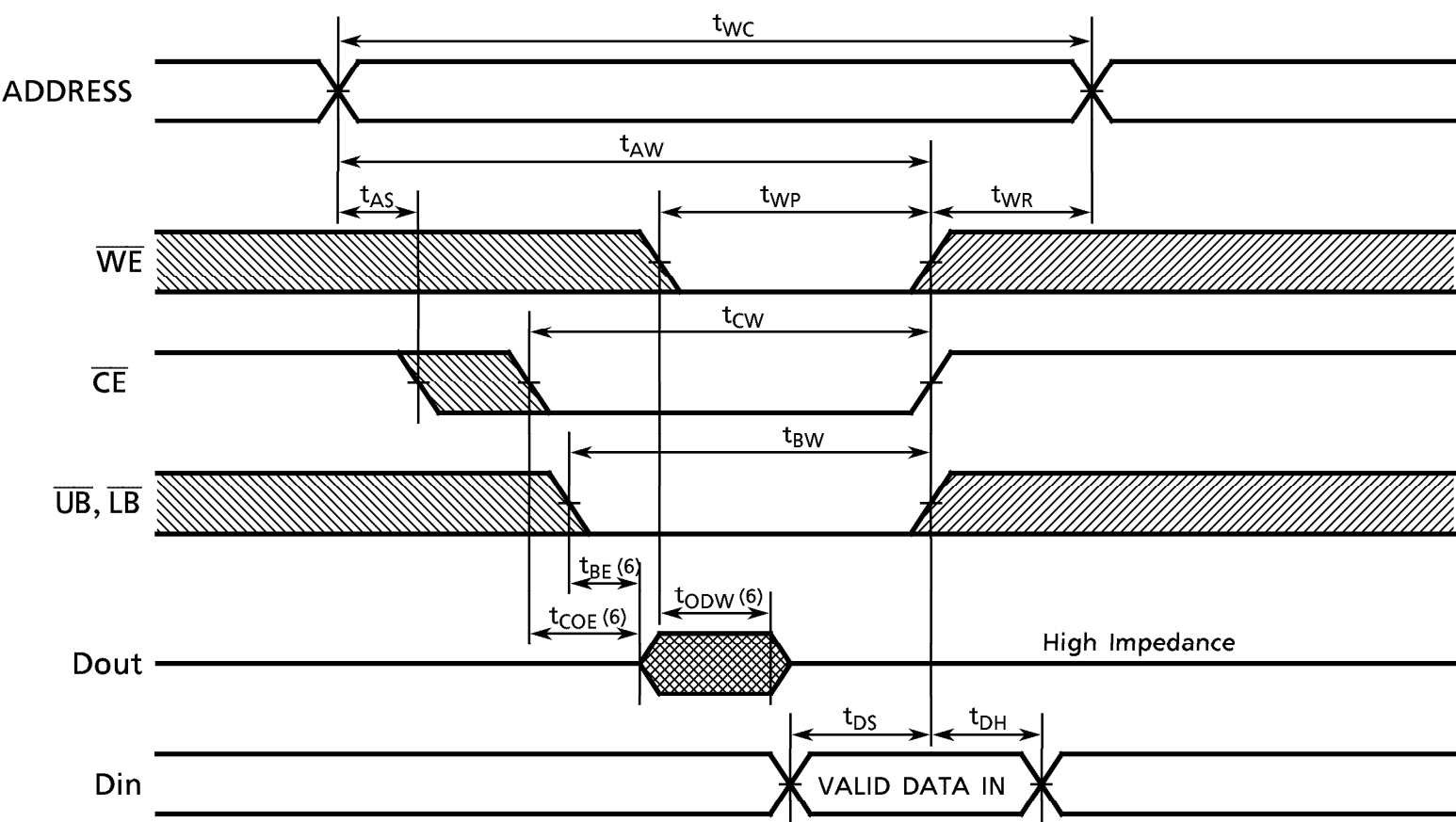
TIMING WAVEFORMS
READ CYCLE (2)



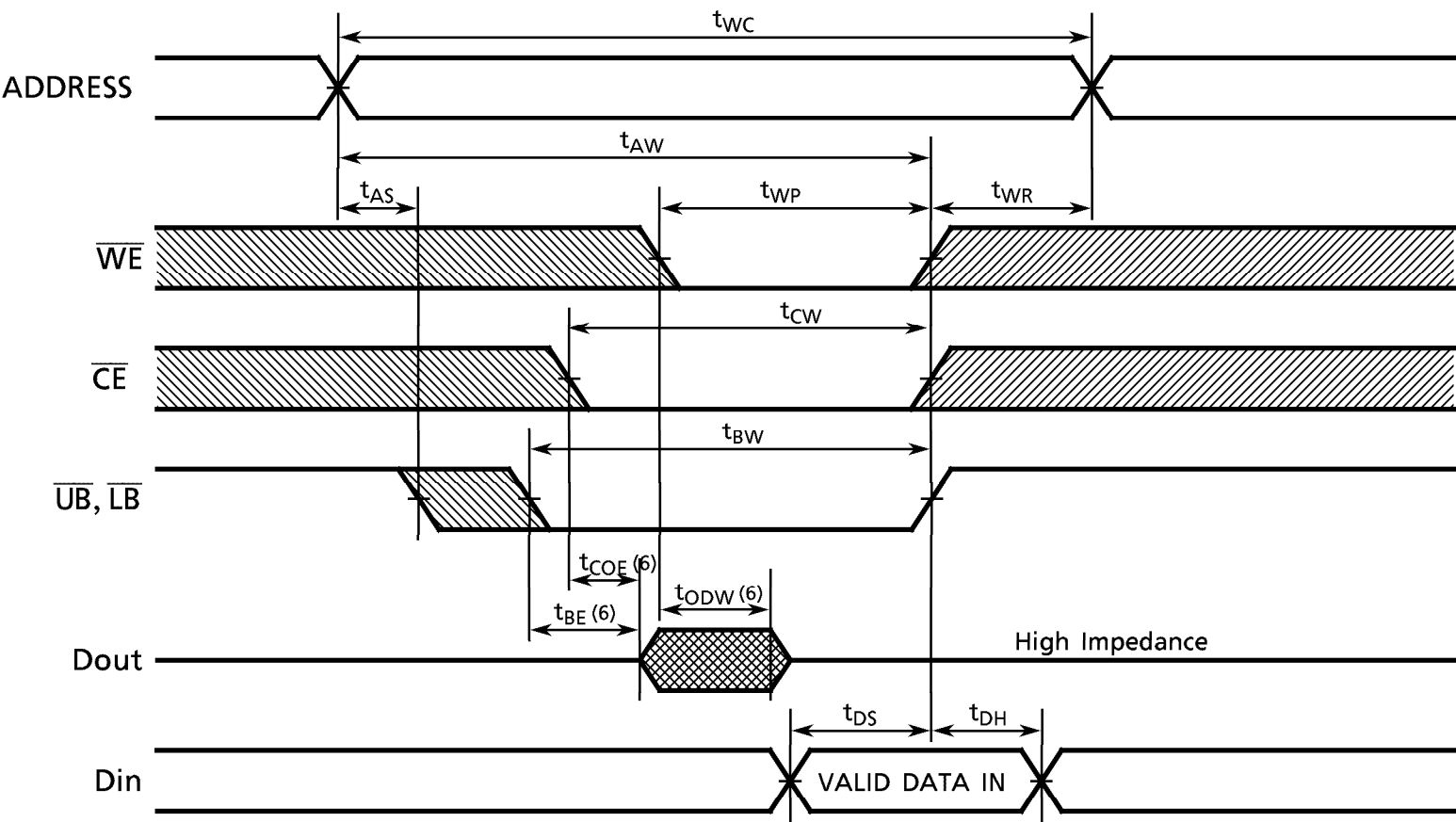
WRITE CYCLE 1 (5) ($\overline{WE}$ Controlled)



WRITE CYCLE 2 (5) ($\overline{CE}$ Controlled)



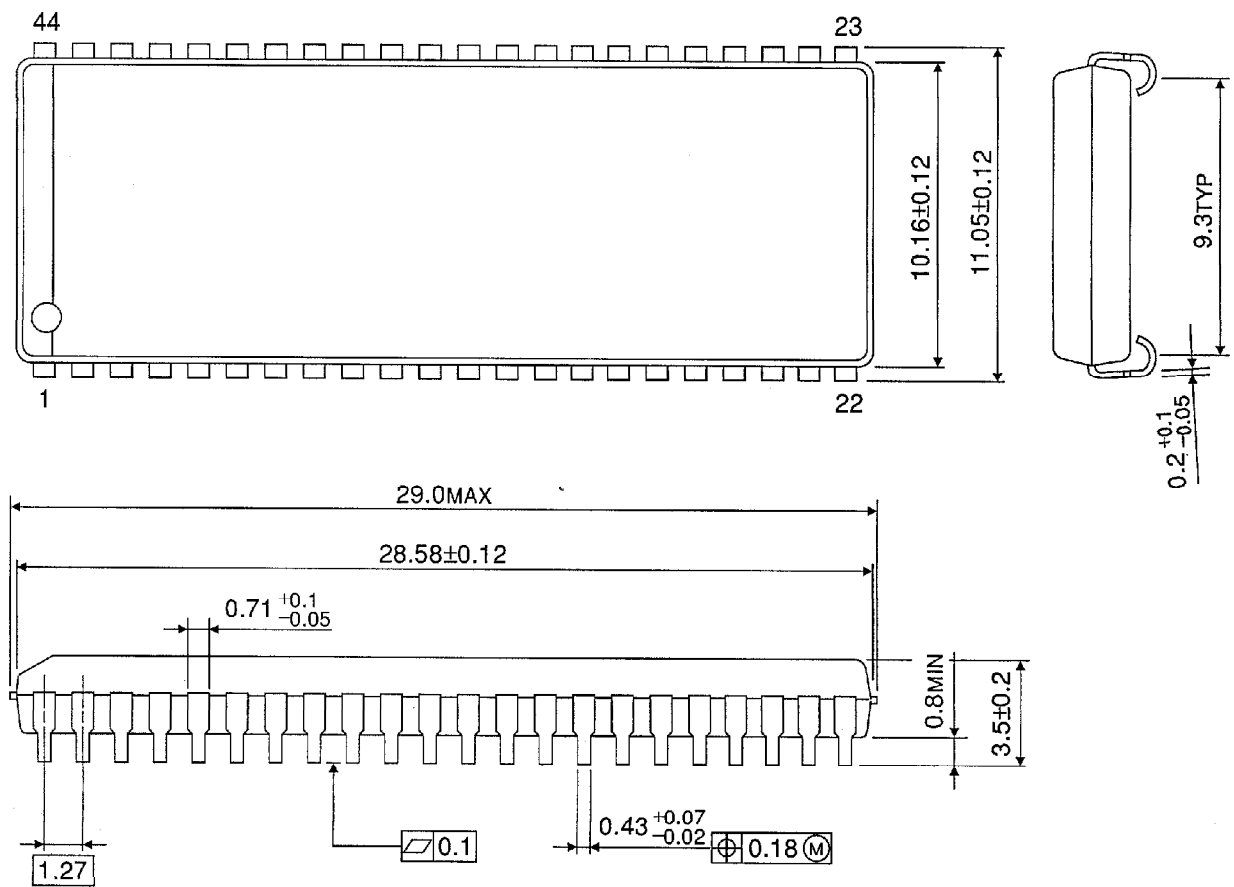
WRITE CYCLE 3 (5) ($\overline{UB}, \overline{LB}$ Controlled)



PACKAGE DIMENSIONS

Plastic SOJ (SOJ44-P-400-1.27)

Unit in mm

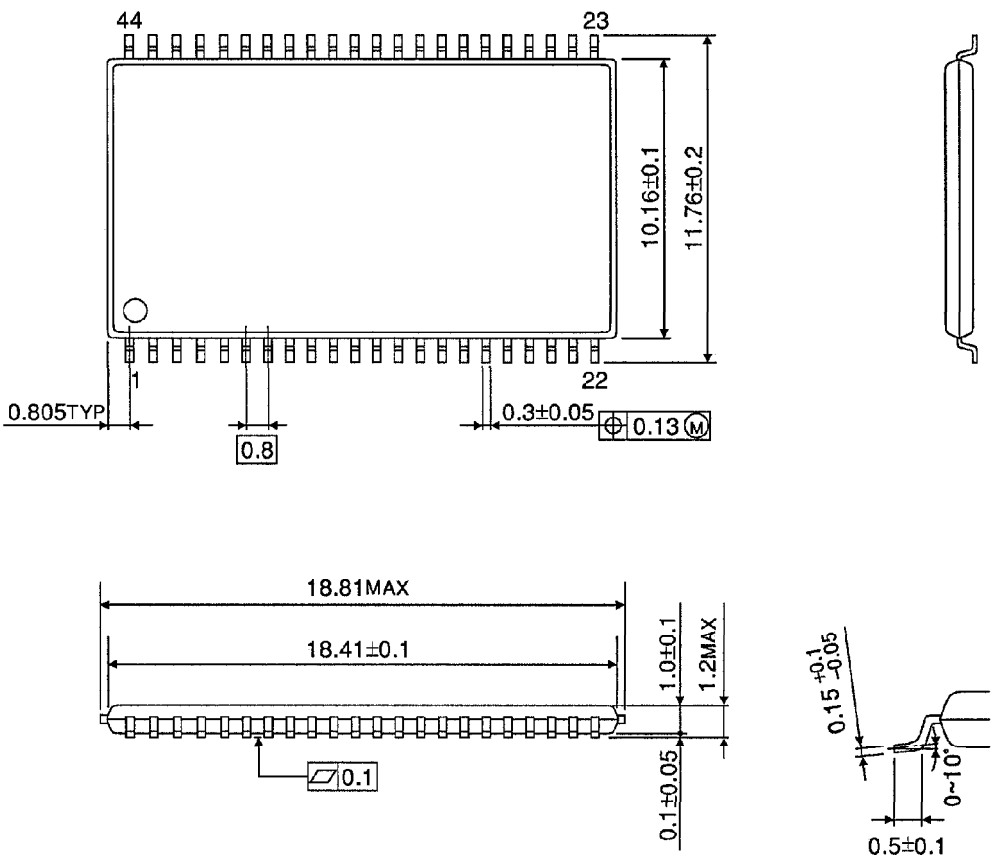


Weight : 1.64g (Typ)

PACKAGE DIMENSIONS

Plastic TSOP (TSOPII 44-P-400-0.80)

Unit in mm



Weight : 0.45g (Typ)